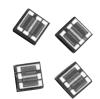
## Vishay Sfernice



# **Dual Value Chip Resistors, Center Tap**



Actual Size

The demand for high precision, high stability microchips for both military and industrial environments is increasing with the growth and sophistication of modern day hybrid circuitry. The need for high accuracy ultra stable micro dividers particularly triggered the development of these third generation nickel chromium microchip dividers which offer standards of accuracy and thermal/time stability never achieved before in the conventional second generation thin metal film technologies.

#### **FEATURES**

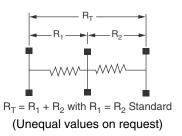
- High precision
- Very low temperature coefficient < 10 ppm/°C</li>
- Excellent stability 0.03 % (2000 h, rated power, at + 70 °C)
- Wirebondable



#### **TYPICAL PERFORMANCE**

	ABS	TRACKING
TCR	5 ppm/°C	1 ppm/°C
	ABS	RATIO
TOL.	0.1 %	0.01 %

#### **SCHEMATICS**



STANDARD ELECTRICAL SPECIFICATIONS				
TEST		SPECIFICATIONS	CONDITIONS	
SERIES		ULTRAFILM®		
Resistance range		1 kΩ to 250 kΩ	$(R_T = R_1 + R_2)$	
TCR:	Tracking	± 1 ppm/°C typical (± 2 ppm/°C maximum)	- 55 °C to + 125 °C	
	Absolute	± 5 ppm/°C maximum ± 10 ppm/°C maximum	0 °C to + 70 °C - 55 °C to + 155 °C	
Tolerance:	Ratio	0.1 %, 0.05 %, 0.02 %, 0.01 %		
	Absolute	± 0.1 %, ± 0.5 %, ± 1 %		
Power rating		125 mW at 25 °C/50 mW at + 70 °C, 25 mW at + 125 °C		
Stability		300 ppm typical	2000 h at + 70 °C under Pn	
Voltage coefficient		< 0.01 ppm/V		
Working voltage		100 V <sub>DC</sub> on R <sub>T</sub>		
Operating ter	nperature range	- 55 °C to + 155 °C <sup>(1)</sup>		
Storage temperature range		- 55 °C to + 155 °C		
Noise		< - 35 dB typical	MIL-STD-202 Method 308	
Thermal EMF		< 0.01 μV/°C		
Shelf life stability		50 ppm	1 year	

#### Note:

<sup>&</sup>lt;sup>(1)</sup> For Temperature up to 200 °C, please consult factory

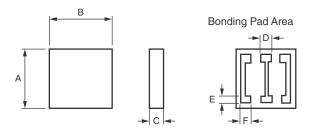
<sup>\*</sup> Please see document "Vishay Green and Halogen-Free Definitions (5-2008)" http://www.vishay.com/doc?99902



## Dual Value Chip Resistors, Center Tap

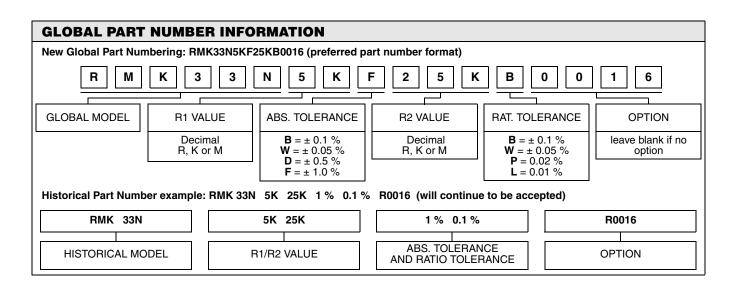
Vishay Sfernice

#### **DIMENSIONS**



DIMENSION	INCHES	MILLIMETERS
Α	0.03 ± 0.004	0.76 ± 0.10
В	0.03 ± 0.004	0.76 ± 0.10
С	0.01 to 0.015	0.25 to 0.40
D	0.006	0.15
E	0.004	0.10
F	0.006	0.15

MECHANICAL SPECIFICATIONS		
Resistive element	Passivated Nichrome	
Substrate material	Silicon (Alumina on request)	
Body	Silcon	
Passivation	Silicone Nitride	
Bonding pads	Aluminum	





Vishay

### **Disclaimer**

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com